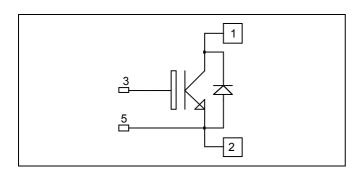


Single switch Trench + Field Stop IGBT3 Power Module

$$V_{CES} = 600V$$

 $I_{C} = 750A$ @ $Tc = 80$ °C



Application

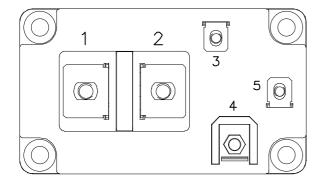
- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- M6 connectors for power
- M4 connectors for signal
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- **RoHS Compliant**



Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		600	V
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	1000	
	Continuous Conector Current	$T_C = 80$ °C	750	A
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	1000	
V_{GE}	Gate – Emitter Voltage		±20	V
P_D	Maximum Power Dissipation	$T_C = 25$ °C	2300	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	1600A@550V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				1	mA
V _{CE(sat)}	Collector Emitter saturation Voltage		$T_j = 25$ °C		1.5	1.9	V
				1.7		v	
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 13mA$		5.0	5.8	6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				3100	nA

Dynamic Characteristics

•	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			49		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			3.1		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz			1.5		
Q_{G}	Gate charge	V_{GE} =-8/+15V, I_{CE} =300V	=800A		5.8		μC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		250		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			70		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 300V$ $I_{C} = 800A$			550		
T_{f}	Fall Time	$R_G = 2\Omega$		70			
$T_{d(on)}$	Turn-on Delay Time		Inductive Switching (150°C)		270		ns
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 800A$ $R_{G} = 2\Omega$			80		
$T_{d(off)}$	Turn-off Delay Time				650		
T_{f}	Fall Time				80		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$	$T_j = 150$ °C		10		I
E_{off}	Turn off Energy	$I_C = 800A$ $R_G = 2\Omega$	$T_j = 150$ °C		40		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 360V$ $t_p = 6\mu s$; $T_i = 150^{\circ}C$			4000		A

Reverse diode ratings and characteristics

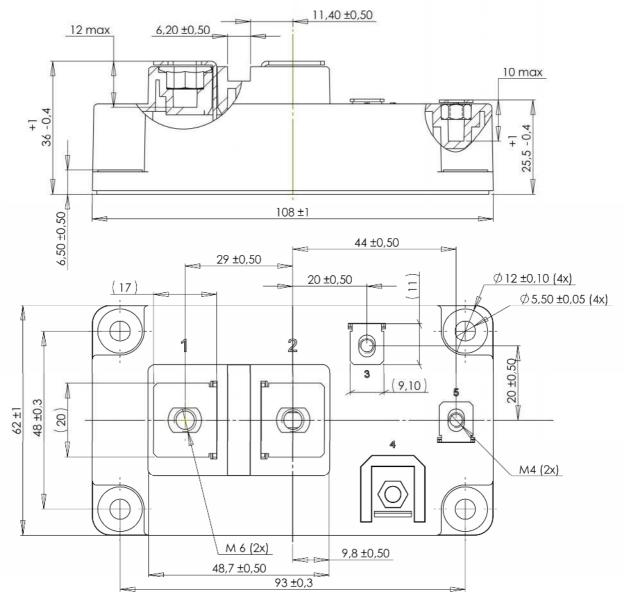
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I_{RRM}	Maximum Reverse Leakage Current	V _R =600V	$T_i = 25$ °C $T_i = 150$ °C			750 1000	μА
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		800		A
V_{F}	Diode Forward Voltage	$I_F = 800A$ $V_{GE} = 0V$	$T_i = 25^{\circ}C$		1.6	2.1	V
v F	Diode Polward Voltage		$T_{i} = 150^{\circ}C$		1.5		
+	Davanga Dagayany Tima		$T_j = 25^{\circ}C$		150		ns
t_{rr}	Reverse Recovery Time		$T_{i} = 150^{\circ}C$		250		
0	Daviana Dagavany Changa	$I_F = 800A$	$T_j = 25$ °C		36		C
Q_{rr}	Reverse Recovery Charge	$V_R = 300V$ di/dt = 5000A/µs	$T_i = 150^{\circ}C$		76		μC
	Reverse Recovery Energy	Т	$T_i = 25^{\circ}C$		9.2		
E_{rr}			$T_i = 150^{\circ}C$		19		mJ



Thermal and package characteristics

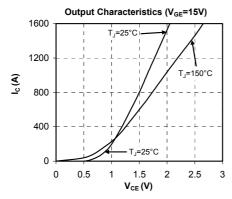
Symbol	Characteristic		Min	Тур	Max	Unit	
D	Junction to Case Thermal Resistance	IGBT			0.065	°C/W	
R_{thJC}		Diode			0.11	C/ VV	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz		4000			V	
T_{J}	Operating junction temperature range		-40		175		
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature		-40		125		
Torque	Mounting torque	M6	3		5	N.m	
		M4	1		2	18.111	
Wt	Package Weight				350	g	

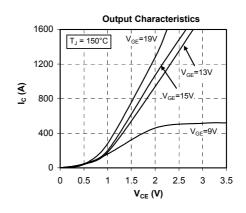
D4 Package outline (dimensions in mm)

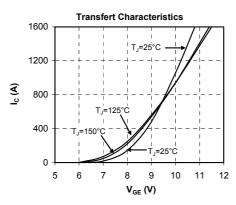


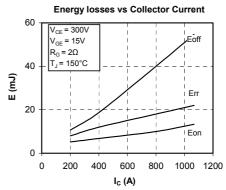


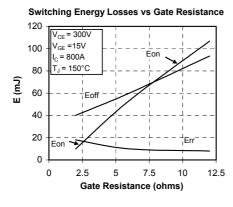
Typical Performance Curve

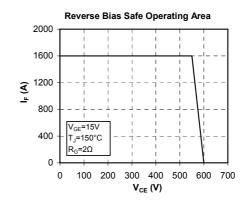


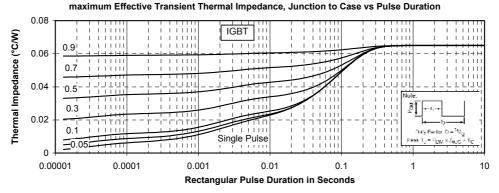




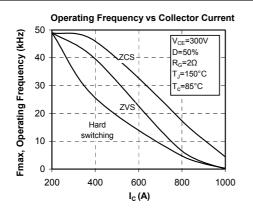


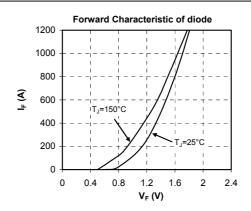


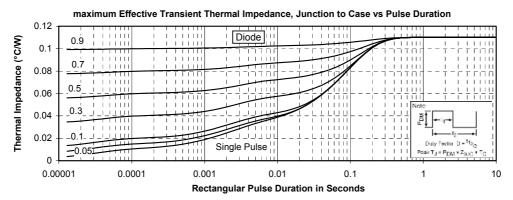














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